

RM747

General Purpose Dual Operational Amplifier

Description

The RM747 integrated circuit is a high gain, operational amplifier internally compensated and constructed on a single silicon chip using an advanced epitaxial process.

The RM747, operates over a temperature range from -55°C to +125°C.

Combining the features of the 741 with the close parameter matching and tracking of a dual device on a monolithic chip results in unique performance characteristics. Excellent channel separation allows the use of the dual device in all single 741 operational amplifier applications providing high packaging density. It is especially well suited for applications in differential-in, differential-out as well as in potentiometric amplifiers and where gain and phase matched channels are mandatory.

Features

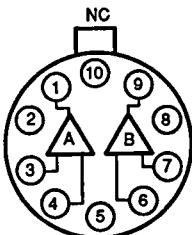
- ◆ Short circuit protection
- ◆ No frequency compensation required
- ◆ No latch-up
- ◆ Large common mode and differential voltage ranges
- ◆ Low power consumption
- ◆ Parameter tracking over temperature range
- ◆ Gain and phase match between amplifiers

Linear

RM747

Connection Information

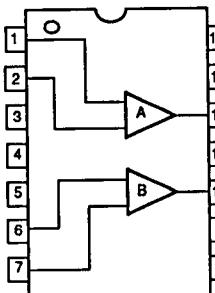
10-Lead TO-100 Metal Can
(Top View)



6S-0872

Pin	Function
1	Output A
2	-V _s A
3	-Input A
4	+Input A
5	-V _s
6	+Input B
7	-Input B
8	+V _s B
9	Output B
10	NC

14-Lead Dual In-Line Package
(Top View)



6S-0873

Pin	Function
1	- Input A
2	+ Input A
3	V _{os} Trim A
4	-V _s
5	V _{os} Trim B
6	+Input B
7	-Input B
8	V _{os} Trim B
9	+V _s B
10	Output B
11	NC
12	Output A
13	+V _s A
14	V _{os} Trim A

Ordering Information

Part Number	Package	Operating Temperature Range
RM747D	D	-55°C to +125°C
RM747D/883B	D	-55°C to +125°C
RM747T	T	-55°C to +125°C
RM747T/883B	T	-55°C to +125°C

Notes:

883B suffix denotes Mil-Std-883, Level B processing

D = 14-lead ceramic DIP

T = 10-lead metal can TO-100

Absolute Maximum Ratings

Supply Voltage

RM747 ±22V

Differential Input Voltage 30V

Input Voltage¹ ±15V

Output Short-Circuit Duration Indefinite
Storage Temperature

Range -65°C to +150°C

Operating Temperature Range

RM747 -55°C to +125°C

Lead Soldering Temperature

(60 sec) +300°C

Notes:

- For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Thermal Characteristics

	14-Lead Ceramic DIP	10-Lead TO-100 Metal Can
Max. Junction Temp.	+175°C	+175°C
Max. P_D $T_A < 50^\circ\text{C}$	1042 mW	658 mW
Therm. Res θ_{JC}	60°C/W	50°C/W
Therm. Res. θ_{JA}	120°C/W	190°C/W
For $T_A > 50^\circ\text{C}$ Derate at	8.33 mW/°C	5.26 mW/°C

Electrical Characteristics

($V_S = \pm 15\text{V}$ and $T_A = +25^\circ\text{C}$ unless otherwise noted)

Parameters	Test Conditions	Min	Typ	Max	Units
Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$		1.0	5.0	mV
Input Offset Current			20	200	nA
Input Bias Current			80	500	nA
Input Resistance (Diff. Mode)		0.3	2.0		MΩ
Large Signal Voltage Gain	$R_L \geq 2\text{ k}\Omega, V_{OUT} = \pm 10\text{V}$	50	200		V/mV
Output Voltage Swing	$R_L \geq 10\text{ k}\Omega$	±12	±14		V
	$R_L \geq 2\text{ k}\Omega$	±10	±13		
Input Voltage Range		±12	±13		V
Common Mode Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	70	90		dB
Power Supply Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	76	90		dB
Power Consumption			100	170	mW
Transient Response					
Rise Time	$V_{IN} = 20\text{ mV}, R_L = 2\text{ k}\Omega$		0.3		μS
Overshoot	$C_L \leq 100\text{ pF}$		5.0		%
Slew Rate	$R_L \geq 2\text{ k}\Omega$		0.5		V/μS
Channel Separation	$F = 1\text{ kHz}$		98		dB

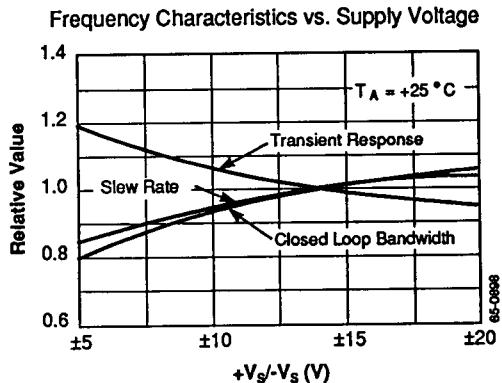
RM747

Electrical Characteristics

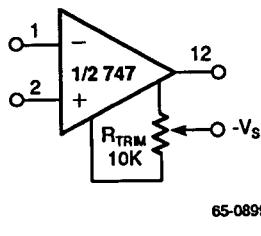
($V_S = \pm 15V$, $-55^\circ C \leq T_A \leq +125^\circ C$)

Parameters	Test Conditions	Min	Typ	Max	Units
Input Offset Voltage	$R_S \leq 10 k\Omega$			6.0	mV
Input Offset Current	$T_A = +125^\circ C$,			200	nA
	$T_A = +70^\circ C$			500	nA
Input Bias Current	$T_A = -55^\circ C$,			500	nA
	$T_A = 0^\circ C$			1500	nA
Large Signal Voltage Gain	$T_A = +125^\circ C$,			500	nA
	$T_A = +70^\circ C$			1500	nA
Output Voltage Swing	$R_L \geq 2 k\Omega$,	25			V/mV
Common Mode Rejection Ratio	$V_{OUT} = \pm 10V$				
	$R_L \geq 10k\Omega$	± 12			V
Power Supply Rejection Ratio	$R_L \geq 2 k\Omega$	± 10			V
	$R_S \leq 10 k\Omega$	70			dB
Power Consumption	$R_S \leq 10 k\Omega$	76		150	dB
Power Consumption	$T_A = +125^\circ C$			150	mW
	$T_A = -55^\circ C$			200	mW
Input Voltage Range		± 12			V

Typical Performance Characteristics



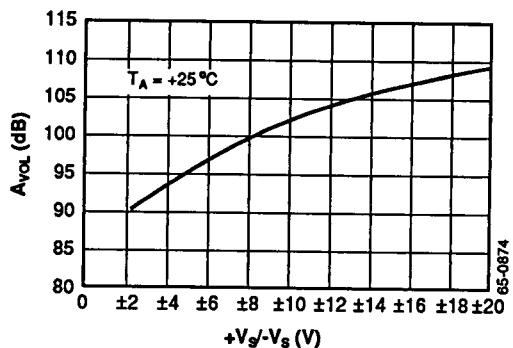
Input Offset Voltage Trim Circuit



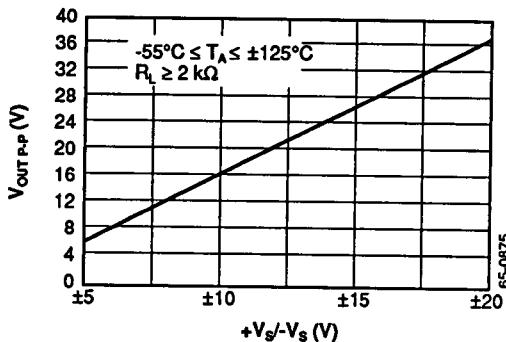
Note: Pin numbers shown are for
14-lead packages

Typical Performance Characteristics (Continued)

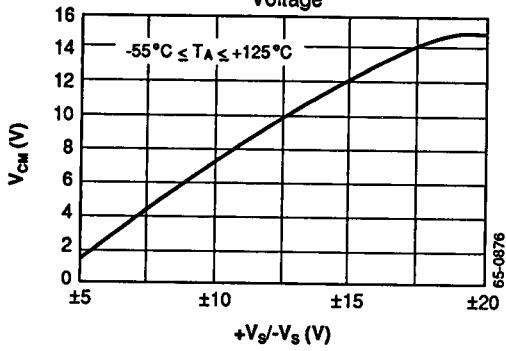
Open Loop Gain vs. Supply Voltage



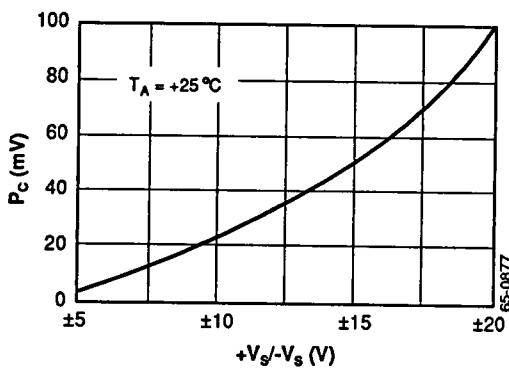
Output Voltage Swing vs. Supply Voltage



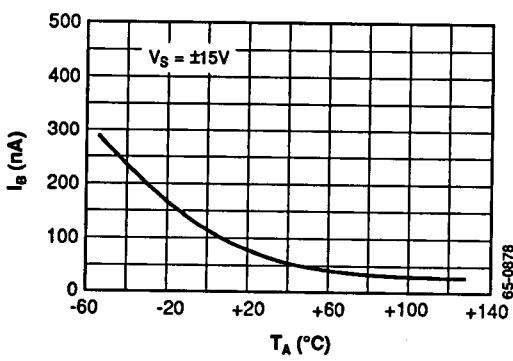
Common Mode Input Range vs. Supply Voltage



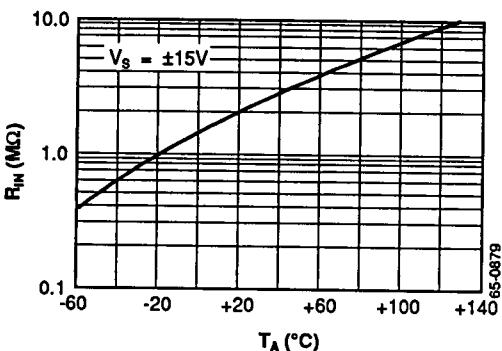
Power Consumption vs. Supply Voltage



Input Bias Current vs. Temperature



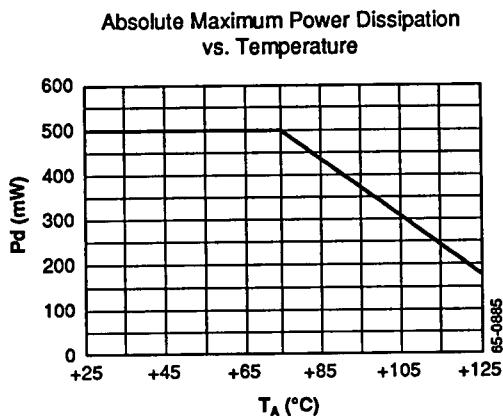
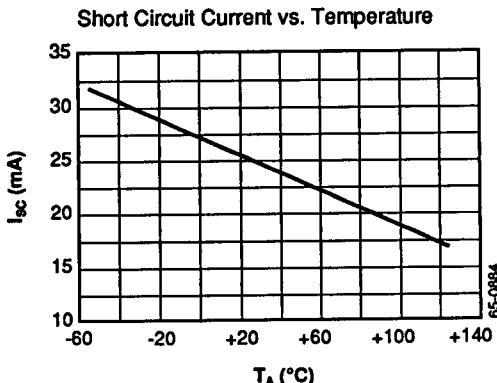
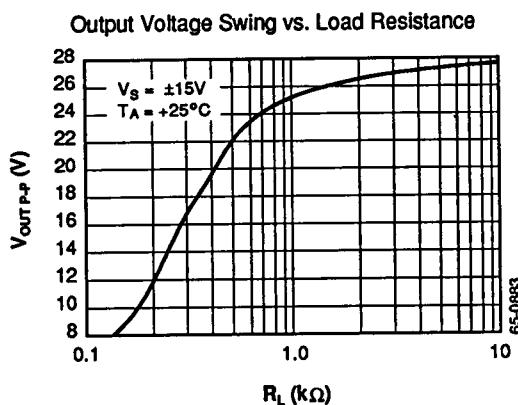
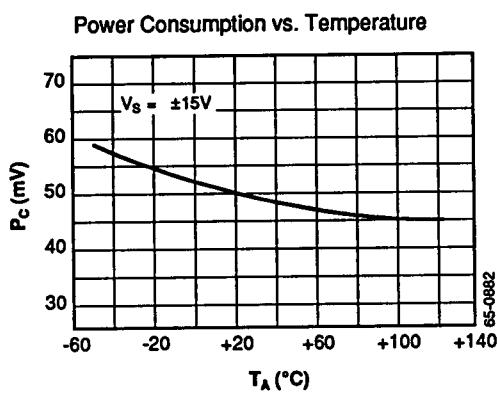
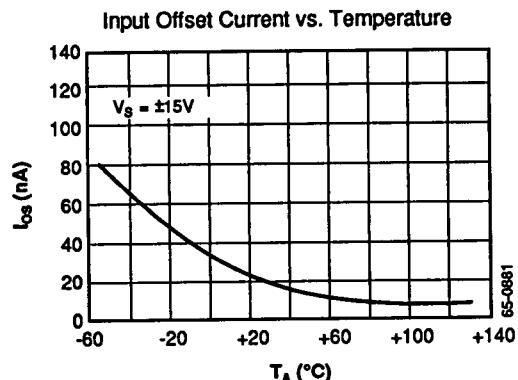
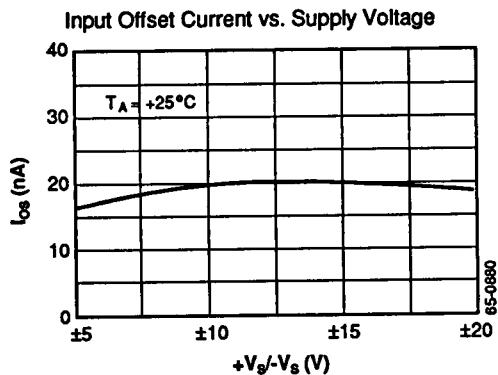
Input Resistance vs. Temperature



Linear

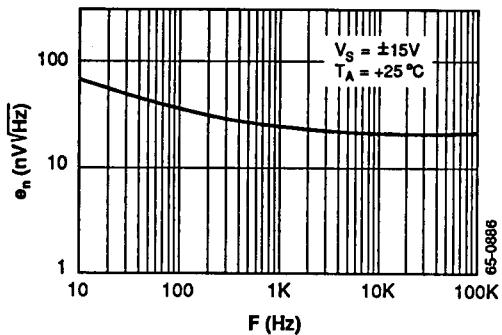
RM747

Typical Performance Characteristics (Continued)

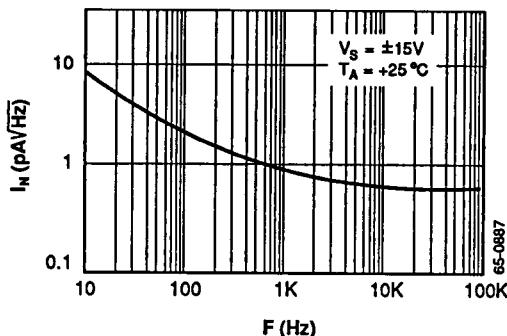


Typical Performance Characteristics (Continued)

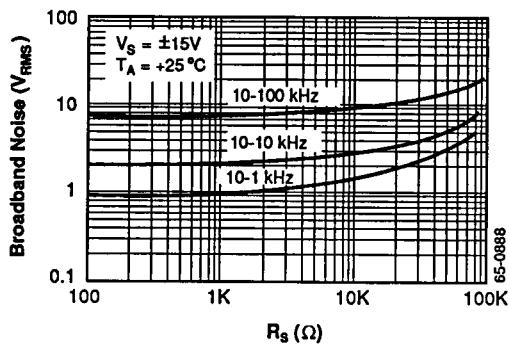
Input Noise Voltage Density vs. Frequency



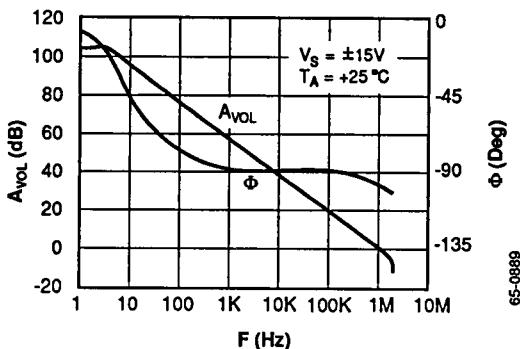
Input Noise Current Density vs. Frequency



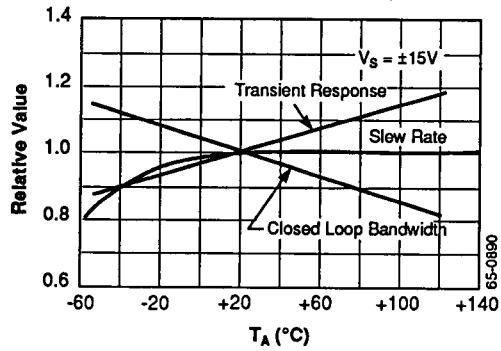
Broadband Noise Referred to Input vs. Source Resistance



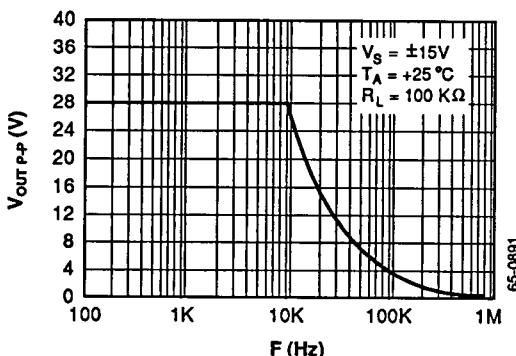
Open Loop Gain, Phase vs. Frequency



Frequency Characteristics vs. Temperature

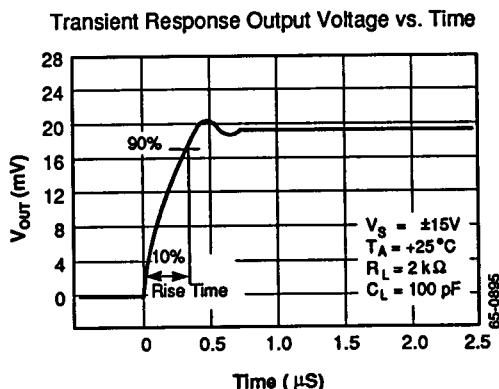
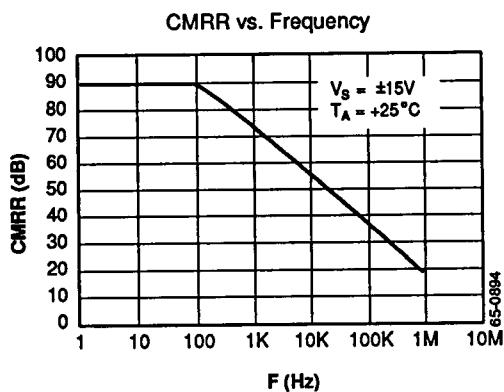
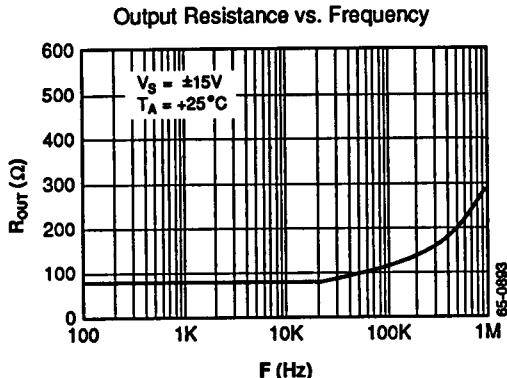
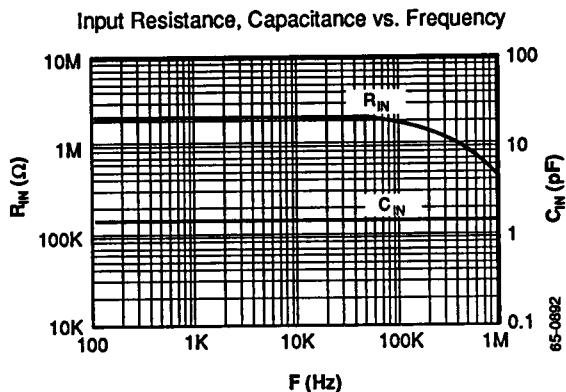


Output Voltage Swing vs. Frequency

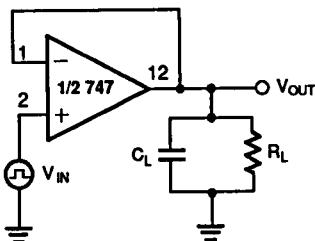


RM747

Typical Performance Characteristics (Continued)



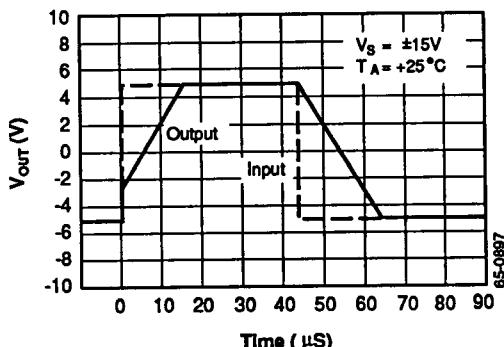
Transient Response Test Circuit



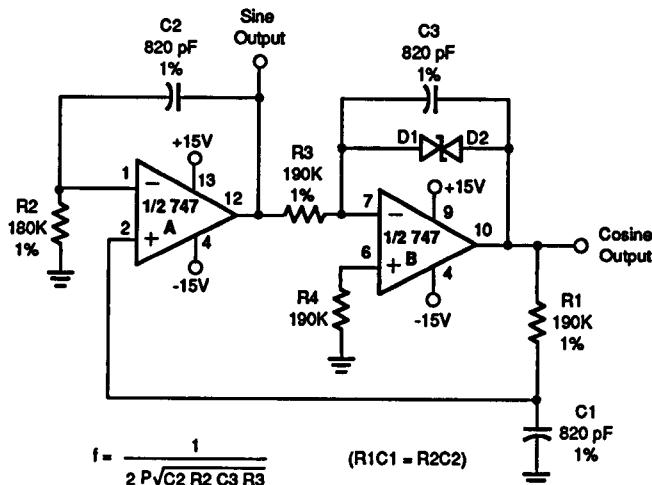
Note: Pin numbers shown are
for 14-lead packages

65-0896

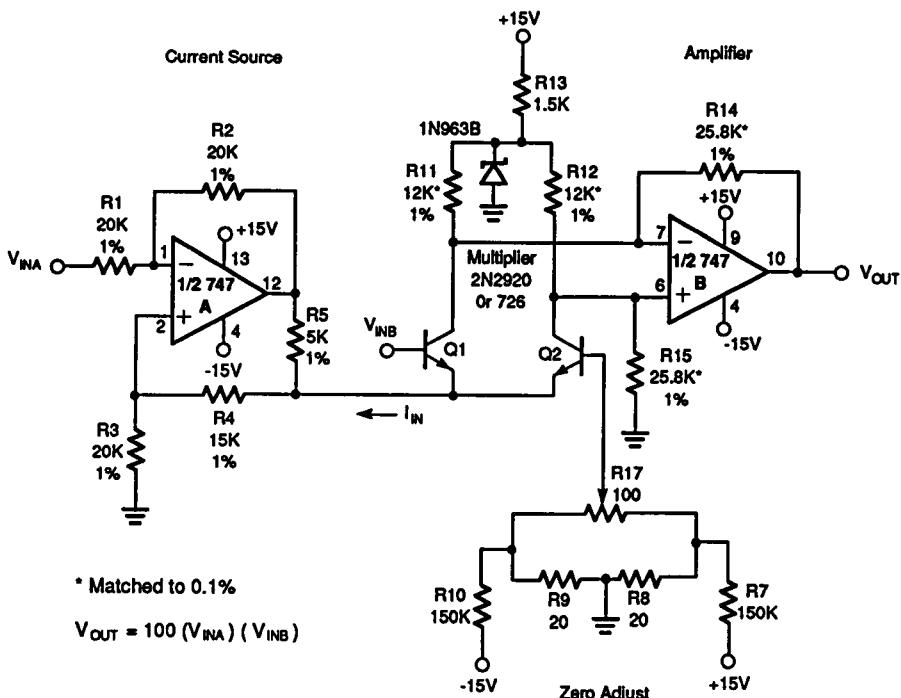
**Follower Large Signal Pulse Response
Output Voltage vs. Time**



Typical Applications



Quadrature Oscillator



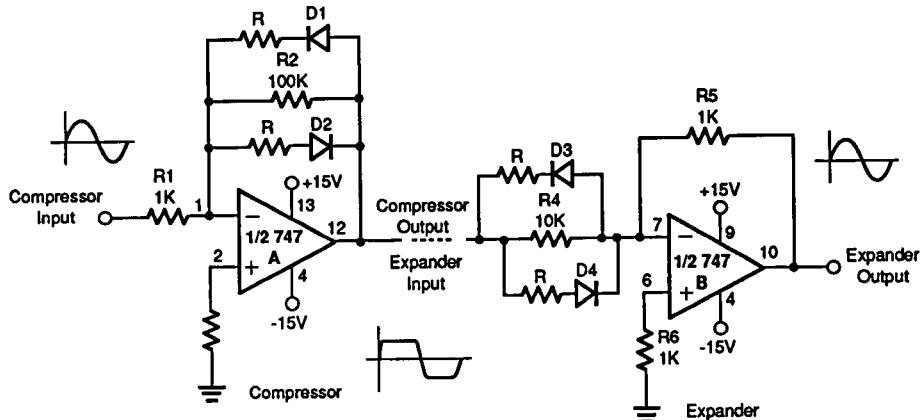
Note: Pin numbers shown are for 14-lead packages

65-0902

Analog Multiplier

RM747

Typical Applications (Continued)

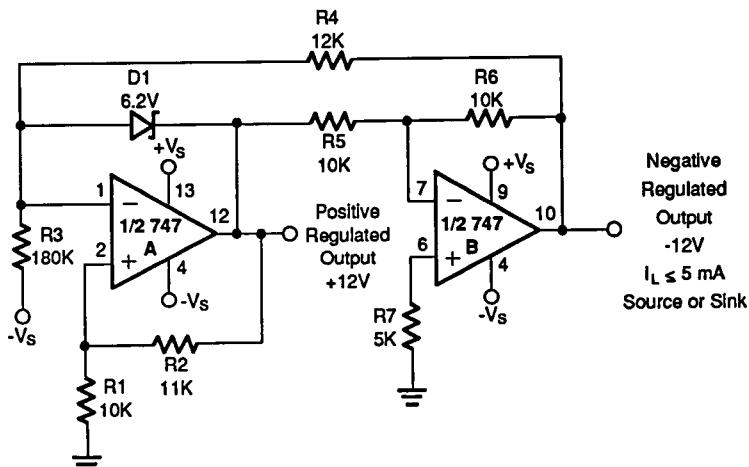


Maximum compressor expansion ratio = R_1/R ($10 \text{ k}\Omega > R \geq 0$)

Note: Diodes D1 through D4 are matched FD6666 or equivalent

65-0903

Compressor/Expander Amplifiers



$$\text{Positive Output} = V_{D1} \times \frac{R1 + R2}{R2}$$

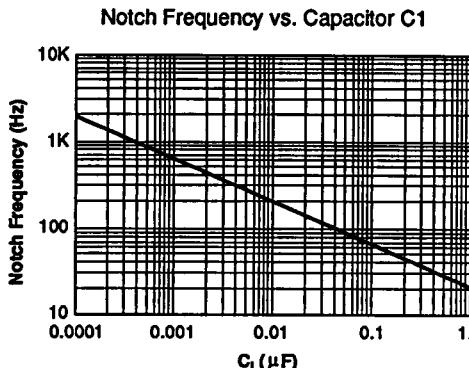
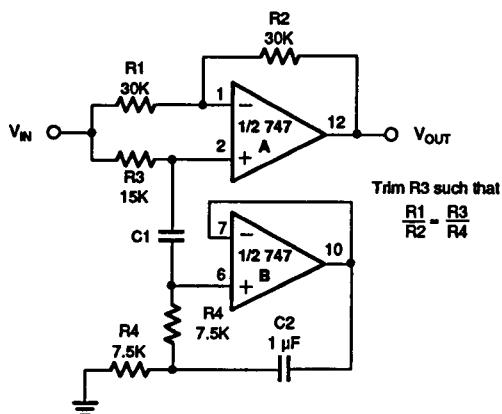
$$\text{Negative Output} = -\text{Positive Output} \times \frac{R6}{R5}$$

65-0904

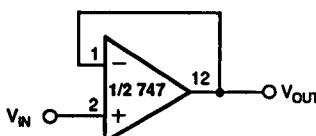
Note: Pin numbers shown are for 14-lead packages.

Tracking Positive and Negative Voltage References

Typical Applications (Continued)

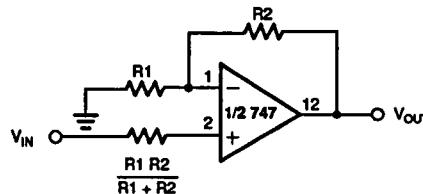


Notch Filter Using the 747 as a Gyrator



$R_{IN} = 400 \text{ M}\Omega$
 $C_{IN} = 1 \text{ pF}$
 $R_{OUT} \leq 1\Omega$
 $BW = 1 \text{ MHz}$

65-0906

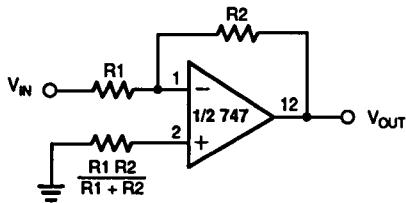


Gain	R_1	R_2	B.W.	R_{IN}
10	1 kΩ	9 kΩ	100 kHz	400 MΩ
100	100 kΩ	9.9 kΩ	10 kHz	280 MΩ
1000	100 kΩ	99.9 kΩ	1 kHz	80 MΩ

65-0907

Unity Gain Voltage Follower

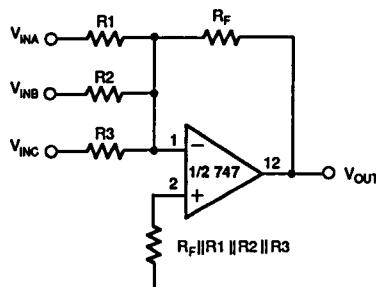
Non-Inverting Amplifier



Gain	R_1	R_2	B.W.	R_{IN}
1	10 kΩ	10 kΩ	1 MHz	10 kΩ
10	1 kΩ	10 kΩ	100 kHz	1 kΩ
100	1 kΩ	100 kΩ	10 kHz	1 kΩ
1000	100 kΩ	100 kΩ	1 kHz	100 kΩ

65-0908

Inverting Amplifier



$$V_{OUT} = -V_{INA} \left(\frac{R_F}{R_1} \right) - V_{INB} \left(\frac{R_F}{R_2} \right) - V_{INC} \left(\frac{R_F}{R_3} \right)$$

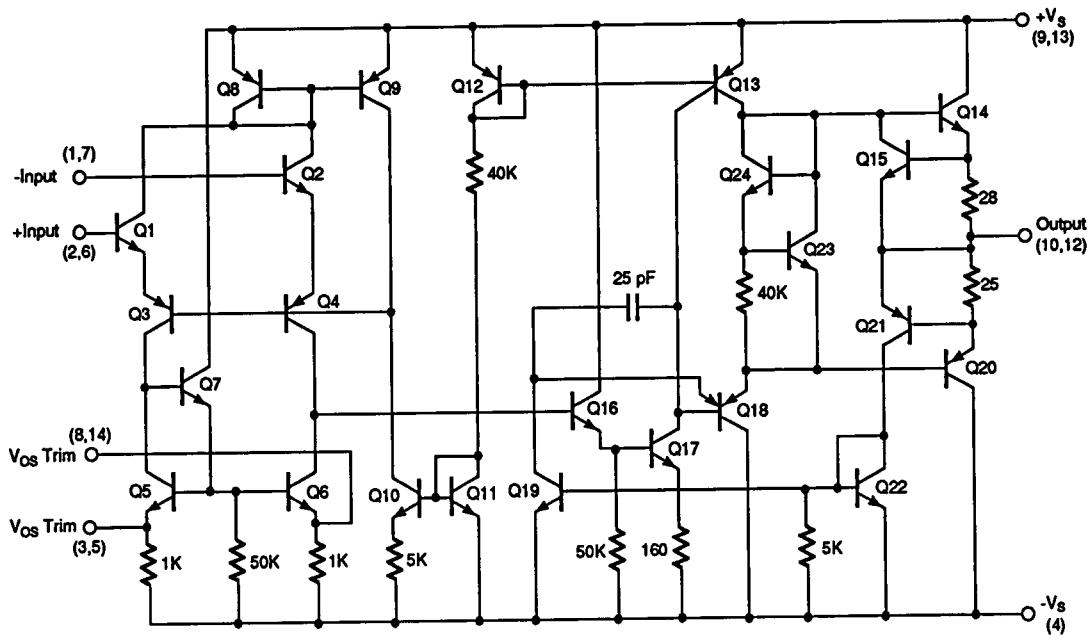
Note: Pin numbers shown are for 14-lead packages

65-0909

Weighted Averaging Amplifier

RM747

Schematic Diagram (1/2 Shown)



Note: Pin numbers shown are for 14-lead packages

65-0871